

08/10/01
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Docket No.: M-7525 US

August 10, 2001

Box Patent Application
Commissioner For Patents
Washington, D. C. 20231

Enclosed herewith for filing is a patent application, as follows:

Inventor(s): Robert Bertran Ogle, Jr. and Arvind Halliyal
Title: Process for Treating ONO Dielectric Film of a Floating Gate Memory Cell
X Return Receipt Postcard
X This Transmittal Letter (in duplicate)
5 page(s) Specification (not including claims)
3 page(s) Claims
1 page Abstract
3 Sheet(s) of Drawings
3 page(s) Declaration For Patent Application and Power of Attorney (unsigned)
1 page NonPublication Request

CLAIMS AS FILED

| For | Number Filed | | Number Extra | | Rate | | Basic Fee |
|--------------|-----------------|-------|-----------------|---|----------|---|-----------|
| Total Claims | 25 | -20 = | 3 | x | \$ 18.00 | = | \$ 710.00 |

| | | | | | | | |
|--------------------|---|------|---|---|------|---|---------|
| Independent Claims | 1 | -3 = | 0 | x | \$80 | = | \$ 0.00 |
|--------------------|---|------|---|---|------|---|---------|

☐ Fee of _____ for the first filing of one or more multiple dependent claims per application \$

☐ Fee for Request for Extension of Time \$

Please make the following charges to Deposit Account 19-2386:

☒ Total fee for filing the patent application in the amount of \$ 800.00
☒ The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment to Deposit Account 19-2386.

EXPRESS MAIL LABEL NO:

EL922456785US

Respectfully submitted,

Matthew J. Spark
Matthew J. Spark
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08/10/01
09/27/01
JC973 U.S. PTO

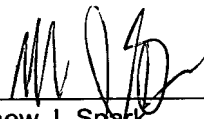
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MODIFIED PTO/SB/35 (11-00)

| | | |
|--|--------------------|--|
| REQUEST AND CERTIFICATION UNDER 35 U.S.C. 122(b)(2)(B)(i) | Inventors | Robert Bertran Ogle, Jr. and Arvind Halliyal |
| | Title | Process for Treating ONO Dielectric Film of a Floating Gate Memory |
| | Atty Docket Number | M-7525 US |

I hereby certify that the invention disclosed in the attached application **has not and will not be** the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing. I hereby request that the attached application not be published under 35 U.S.C. 122(b).

Date


Matthew J. Spark
Attorney for Applicants
Reg. No.: 43,453

This request must be signed in compliance with 37 CFR 1.33(b) and submitted with the application **upon filing**.

Applicant may rescind this nonpublication request at any time. If applicant rescinds a request that an application not be published under 35 U.S.C. 122(b), the application will be scheduled for publication at eighteen months from the earliest claimed filing date for which a benefit is claimed.

If applicant subsequently files an application directed to the invention disclosed in the attached application in another country, or under a multilateral international agreement, that requires publication of applications eighteen months after filing, the applicant **must** notify the United States Patent and Trademark Office of such filing within forty-five (45) days after the date of the filing of such foreign or international application. **Failure to do so will result in abandonment of this application (35 U.S.C. 122(b)(2)(B)(iii)).**

7 CFR 1.213(a) provides for a request that an application not be published under 35 U.S.C. 122(b). Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. SEND TO: Commissioner for Patents, Washington, DC 20231.